



Bipolar PNP Bare Die – BTP6996

Part Description

The BTP6996 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = -25V
- VCEO = -20V
- VEBO = -4V
- hFE = 150-800 @ VCE = -4V, IC = -0.1A
- VCE(Sat) = -0.5V @ IC = -0.5A, IB = -25mA
- fT = 180 MHz @ VCE = -6V, IE = 0A
- COBO = - pF @ VCB = - V

Features

Low VCE(sat). Designed to provide performance equivalent to 2SA2188

Die Size (Unsawn)

390µm X 390µm, 15 Mils X 15 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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